# 74CB3Q3257

# 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump Rev. 2 — 11 April 2024 Product data sheet

### 1. General description

The 74CB3Q3257 is a quad high-bandwidth single-pole, double-throw FET bus switch. The device features one select input (S) and one output enable input ( $\overline{OE}$ ). The switch is disabled when the  $\overline{OE}$  input is HIGH. An internal charge-pump increases the gate voltage of the NMOS pass transistor. The result is improved R<sub>ON</sub> and R<sub>ON(flat)</sub> performance and the ability to switch 5 V signals when V<sub>CC</sub> = 3.3 V.

### 2. Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- Overvoltage switching on switch ports:
  - 0 V to 5 V switching with V<sub>CC</sub> = 2.5 V
  - 0 V to 5 V switching with V<sub>CC</sub> = 3.3 V
- 4 Ω (typical) ON resistance
- 3.5 pF (typical) OFF-state capacitance
- High bandwidth 0.5 GHz (maximum)
- Low input/output capacitance minimizes loading and signal distortion
- Fast switching frequency f<sub>max</sub> = 20 MHz (maximum)
- Low power consumption I<sub>CC</sub> = 0.4 mA (typical)
- Control inputs can be driven by TTL or 5 V/3.3 V CMOS outputs
- · I<sub>OFF</sub> supports partial power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78E Class II Level A
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C

### 3. Applications

- · Communication infrastructure
- Bus isolation
- Memory interleaving
- Sensor multiplexing



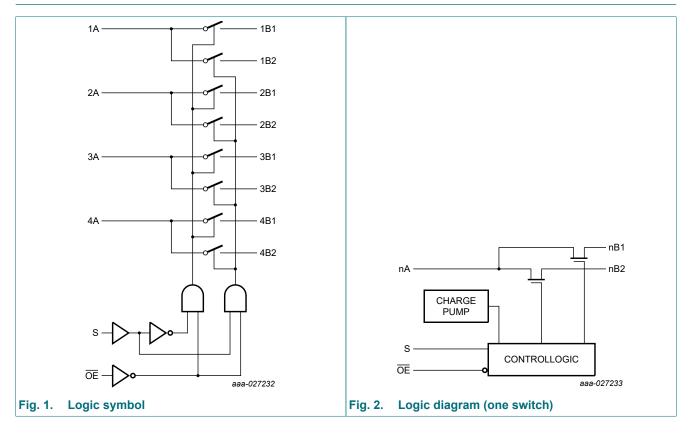
### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

# 4. Ordering information

**Table 1. Ordering information** 

Type number	Package						
Temperature range Name		Name	Description	Version			
74CB3Q3257PW	-40 °C to +85 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1			
74CB3Q3257BQ	-40 °C to +85 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm	SOT763-1			

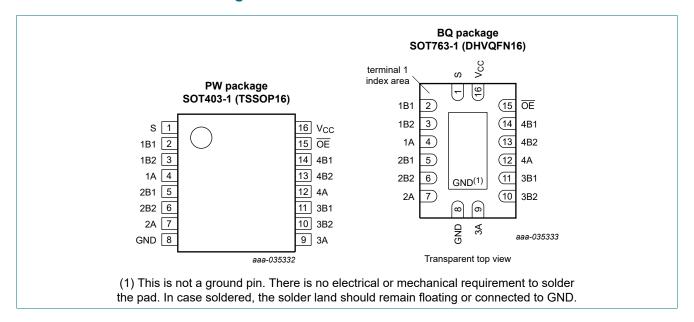
# 5. Functional diagram



#### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

### 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
S	1	select input
1B1, 1B2, 2B1, 2B2, 3B2, 3B1, 4B2, 4B1	2, 3, 5, 6, 10, 11, 13, 14	independent input or output
1A, 2A 3A, 4A	4, 7 9, 12	common output or input
GND	8	ground (0 V)
OE	15	output enable input (active-LOW)
Vcc	16	supply voltage

## 7. Functional description

### Table 3. Function table

 $H = HIGH \text{ voltage level}; L = LOW \text{ voltage level}; X = don't care; Z = high-impedance OFF-state.}$ 

Input	Channel on	
S	OE	
L	L	nA = nB1
Н	L	nA = nB2
Х	Н	Z (switch off)

### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

### 8. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
VI	input voltage	S, $\overline{\text{OE}}$ input [1]	-0.5	+7.0	V
V <sub>SW</sub>	switch voltage	[2]	-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V	-50	-	mA
I <sub>SK</sub>	switch clamping current	V <sub>I</sub> < -0.5 V	-50	-	mA
I <sub>SW</sub>	switch current		-	±120	mA
I <sub>CC</sub>	supply current		-	+100	mA
I <sub>GND</sub>	ground current		-100	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +85  ^{\circ}\text{C}$ [3]	-	500	mW

<sup>[1]</sup> The minimum input voltage rating may be exceeded if the input current rating is observed.

### 9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		2.3	3.6	V
VI	input voltage	S, <del>OE</del> input	0	5.5	V
V <sub>SW</sub>	switch voltage		0	5.5	V
T <sub>amb</sub>	ambient temperature		-40	+85	°C
Δt/ΔV	input transition rise and fall rate	S, <del>OE</del> input			
		V <sub>CC</sub> = 2.3 V to 2.7 V	0	20	ns/V
		V <sub>CC</sub> = 2.7 V to 3.6 V	0	10	ns/V

<sup>[2]</sup> The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

<sup>[3]</sup> For SOT403-1 (TSSOP16) package: P<sub>tot</sub> derates linearly with 8.5 mW/K above 91 °C. For SOT763-1 (DHVQFN16) package: P<sub>tot</sub> derates linearly with 11.2 mW/K above 106 °C.

### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

### 10. Static characteristics

#### **Table 6. Static characteristics**

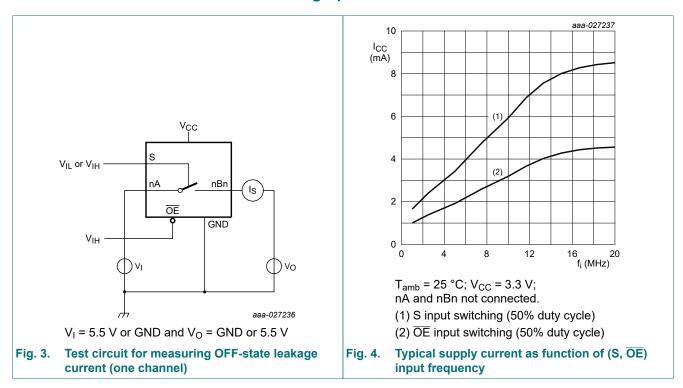
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions		<sub>amb</sub> = 25 °	C	T <sub>amb</sub> =-40 °	°C to +85°C	Unit
			Min	Typ[1]	Max	Min	Max	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	-	1.7	-	V
	input voltage	V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	-	2	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	-	-	0.7	V
	input voltage	V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	-	-	0.8	V
$V_{IK}$	input clamping voltage	nA, nBn; V <sub>CC</sub> = 3.6 V; I <sub>I</sub> = -18 mA	-	-	-	-	-1.8	V
l <sub>1</sub>	input leakage current	S, <del>OE</del> ; V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = GND to 5.5 V	-	-	-	-	±1	μΑ
I <sub>OFF</sub>	power-off leakage current	per pin; $V_{CC} = 0 \text{ V}$ ; $V_{SW}$ or $V_I = 0 \text{ V}$ to 5.5 V	-	-	-	-	±1	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage current	nA, nBn; $V_{CC}$ = 3.6 V; see Fig. 3	-	-	-	-	±1	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{SW}$ = GND or $V_{CC}$ ; $V_{CC}$ = 3.6 V	-	0.4	-	-	0.6	mA
ΔI <sub>CC</sub>	additional supply current	S, $\overline{\text{OE}}$ ; V <sub>CC</sub> = 3.6 V; one input at 3 V, other inputs at GND or V <sub>CC</sub>	-	-	-	-	30	μΑ
Cı	input capacitance	$V_{CC}$ = 3.3 V; $V_{SW}$ = GND or $V_{CC}$ ; $V_1$ = 0 V, 3.3 V, 5.5 V						
		S, <del>OE</del>	-	2.5	-	-	3.5	pF
C <sub>S(OFF)</sub>	OFF-state	V <sub>CC</sub> = 3.3 V; V <sub>SW</sub> = 0 V, 3.3 V, 5.5 V						
	capacitance	nA	-	5.5	-	-	7	pF
		nBn	-	3.5	-	-	5	pF
C <sub>S(ON)</sub>	ON-state	V <sub>CC</sub> = 3.3 V; V <sub>SW</sub> = 0 V, 3.3 V, 5.5 V						
	capacitance	nA, nBn	-	10.5	-	-	13	pF

<sup>[1]</sup> Typical values are measured at  $V_{CC}$  = 3.3 V unless otherwise specified.

#### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

### 10.1. Test circuit and graph



### 10.2. ON resistance

Table 7. ON resistance

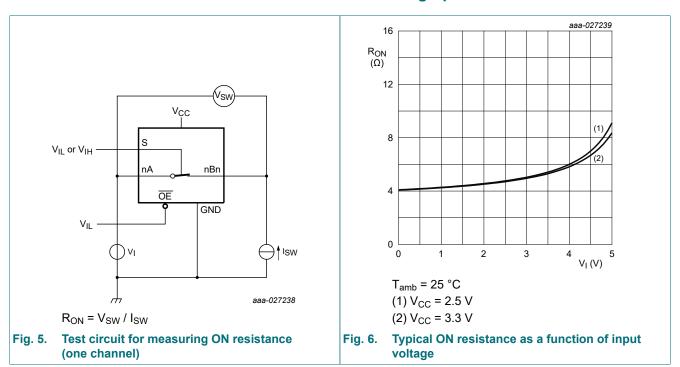
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5.

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °	C Unit		
			Min	Тур	Max	Min	Max	
R <sub>ON</sub>	ON resistance	V <sub>CC</sub> = 2.3 V; see <u>Fig. 6</u>						
		$V_I = 0 V; I_{SW} = 30 \text{ mA}$ [1]	-	4	-	-	8	Ω
		V <sub>I</sub> = 1.7 V; I <sub>SW</sub> = -15 mA [1]	-	4.4	-	-	9	Ω
		V <sub>CC</sub> = 3.0 V; see <u>Fig. 6</u>						
		V <sub>I</sub> = 0 V; I <sub>SW</sub> = 30 mA [2]	-	4	-	-	6	Ω
		V <sub>I</sub> = 2.4 V; I <sub>SW</sub> = -15 mA [2]	-	4.7	-	-	8	Ω

Typical values are measured at  $V_{CC}$  = 2.5 V. Typical values are measured at  $V_{CC}$  = 3.3 V.

### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

### 10.3. ON resistance test circuit and graph



### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

# 11. Dynamic characteristics

**Table 8. Dynamic characteristics** 

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 9.

Symbol	Parameter	Conditions	T <sub>amb</sub> = -40	°C to +85 °C	Unit
			Min	Max	
t <sub>pd</sub>	propagation	nA to nBn or nBn to nA; see Fig. 7 [1][2]			
	delay	V <sub>CC</sub> = 2.3 V to 2.7 V	-	0.12	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	0.20	ns
		S to nA; see Fig. 7 [1]			
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.5	6.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	5.5	ns
t <sub>en</sub>	enable time	OE to nA, nBn; see Fig. 8 [1]			
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.5	6.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	5.5	ns
		S to nBn; see Fig. 8 [1]			
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.5	6.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.5	5.5	ns
t <sub>dis</sub>	disable time	OE to nA, nBn; see Fig. 8 [1]			
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.0	6.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	6.0	ns
		S to nBn; see Fig. 8 [1]			
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.0	6.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	6.0	ns
f <sub>max</sub>	maximum	S, $\overline{OE}$ ; $V_O > V_{CC}$ ; $V_I = 5 \text{ V}$ ; $R_L \ge 1 \text{ M}\Omega$ ; $C_L = 0 \text{ pF}$			
	frequency	V <sub>CC</sub> = 2.3 V to 2.7 V	-	10	MHz
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	20	MHz

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

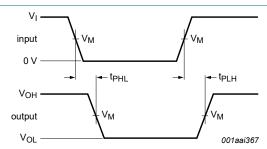
 $t_{\text{en}}$  is the same as  $t_{\text{PZL}}$  and  $t_{\text{PZH}}.$ 

 $t_{\text{dis}}$  is the same as  $t_{\text{PLZ}}$  and  $t_{\text{PHZ}}.$ 

<sup>[2]</sup> The propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

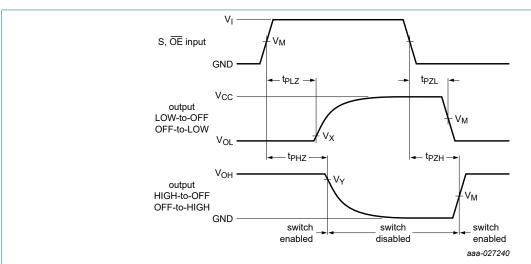
### 11.1. Waveforms and test circuit



Measurement points are given in Table 9.

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 7. The data input (nA or nBn) to output (nBn or nA) propagation delays



Measurement points are given in Table 9.

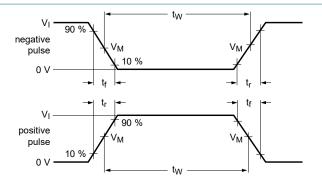
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

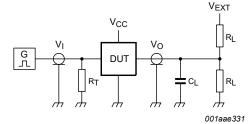
Fig. 8. Enable and disable times

**Table 9. Measurement points** 

Supply voltage	Input	Output	Output			
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>		
2.3 V to 2.7 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V		
3.0 V to 3.6 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V		

### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump





Test data is given in Table 10.

Definitions for test circuit:

 $R_L$  = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

Fig. 9. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input		Load		V <sub>EXT</sub>		
V <sub>CC</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	CL	$R_L$	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PLZ</sub> , t <sub>PZL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>
2.3 V to 2.7 V	V <sub>CC</sub>	≤ 2.5 ns	30 pF	500 Ω	open	2 × V <sub>CC</sub>	GND
3.0 V to 3.6 V	V <sub>CC</sub>	≤ 2.5 ns	50 pF	500 Ω	open	2 × V <sub>CC</sub>	GND

### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

# 12. Package outline

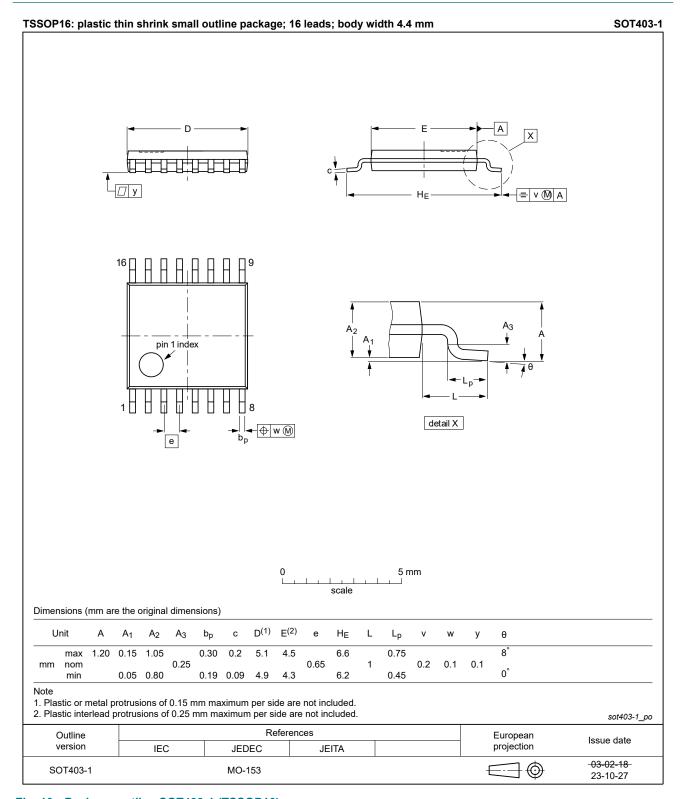


Fig. 10. Package outline SOT403-1 (TSSOP16)

### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

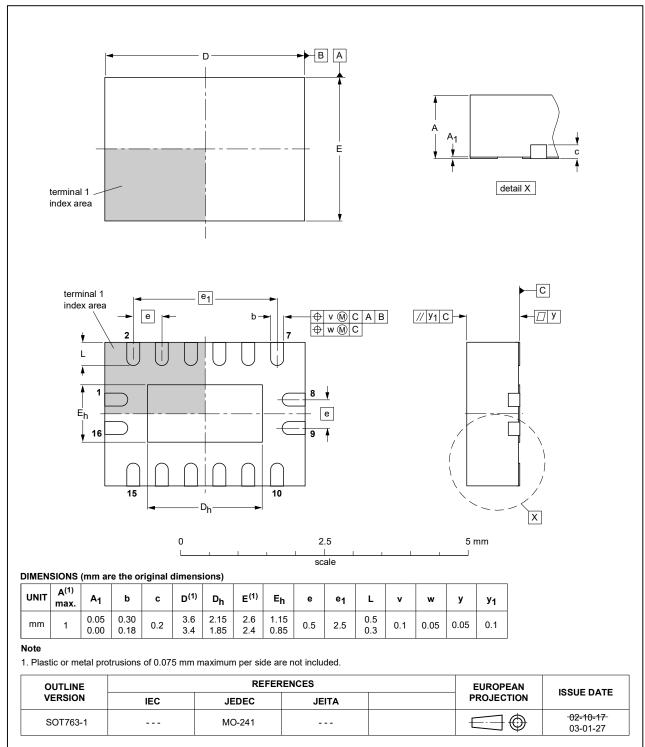


Fig. 11. Package outline SOT763-1 (DHVQFN16)

### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

### 13. Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
FET	Field-Effect Transistor
HBM	Human Body Model
NMOS	N-channel Metal-Oxide Semiconductor
TTL	Transistor-Transistor Logic

# 14. Revision history

### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74CB3Q3257 v.2	20240411	Product data sheet	-	74CB3Q3257 v.1		
Modifications:	<ul> <li>Fig. 10: Aligned TSSOP package outline drawing to JEDEC MO-153.</li> <li>Section 2: ESD specification updated according to the latest JEDEC standard.</li> </ul>					
74CB3Q3257 v.1	20170814	Product data sheet	-	-		

#### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

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#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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### 4-bit 1-of-2 FET multiplexer/demultiplexer with charge pump

### **Contents**

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Ordering information	2
5. Functional diagram	2
6. Pinning information	3
6.1. Pinning	
6.2. Pin description	3
7. Functional description	
8. Limiting values	
Recommended operating conditions	
10. Static characteristics	
10.1. Test circuit and graph	
10.2. ON resistance	
10.3. ON resistance test circuit and graph	
11. Dynamic characteristics	
11.1. Waveforms and test circuit	
12. Package outline	
13. Abbreviations	
14. Revision history	
15. Legal information	
10. Logui illoilliatioil	

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15 / 15

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